





PNP SURFACE MOUNT TRANSISTOR

Features

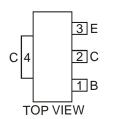
- Epitaxial Planar Die Construction
- Complementary NPN Type Available (DXT3904)
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)

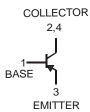
Mechanical Data

- Case: SOT89-3L
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish Matte Tin annealed over Copper leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Marking & Type Code Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.072 grams (approximate)



SOT89-3L





Schematic and Pin Configuration

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-40	V
Collector-Emitter Voltage	V _{CEO}	-40	V
Emitter-Base Voltage	V_{EBO}	-5.0	V
Collector Current – Continuous	Ic	-200	mA

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3) @ T _A = 25°C	P _D	1	W
Thermal Resistance, Junction to Ambient Air (Note 3) @ T _A = 25°C	$R_{ heta JA}$	125	°C/W
Operating and Storage Temperature Range	T _i , T _{STG}	-55 to +150	°C

Notes: 1. No purposefully added lead.

2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.

3. Device mounted on FR-4 PCB; pad layout as shown on page 4 or in Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.



Electrical Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 4)						
Collector-Base Breakdown Voltage	V _(BR) CBO	-40	_	V	$I_C = -10\mu A, I_E = 0$	
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	-40		V	$I_C = -1.0 \text{mA}, I_B = 0$	
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	-5.0		V	$I_E = -10\mu A, I_C = 0$	
Collector Cutoff Current	I _{CEX}		-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = -3.0V$	
	I _{CBO}		-50	nA	$V_{CB} = -30V, I_{E} = 0$	
Base Cutoff Current	I _{BL}		-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = -3.0V$	
ON CHARACTERISTICS (Note 4)						
		60	_		$I_C = -100 \mu A$, $V_{CE} = -1.0 V$	
		80	_		$I_C = -1.0 \text{mA}, V_{CE} = -1.0 \text{V}$	
DC Current Gain	h _{FE}	100	300	_	$I_C = -10 \text{mA}, V_{CE} = -1.0 \text{V}$	
		60	_		$I_C = -50 \text{mA}, V_{CE} = -1.0 \text{V}$	
		30	_		$I_C = -100 \text{mA}, V_{CE} = -1.0 \text{V}$	
Collector-Emitter Saturation Voltage	\/		-0.25	V	$I_C = -10 \text{mA}, I_B = -1.0 \text{mA}$	
Collector-Emitter Saturation Voltage	V _{CE} (SAT)	_	-0.40	V	$I_C = -50 \text{mA}, I_B = -5.0 \text{mA}$	
Base-Emitter Saturation Voltage	\/\c\-	-0.65	-0.85	V	$I_C = -10 \text{mA}, I_B = -1.0 \text{mA}$	
Dase-Emilier Saturation Voltage	V _{BE(SAT)}	_	-0.95		$I_C = -50 \text{mA}, I_B = -5.0 \text{mA}$	
SMALL SIGNAL CHARACTERISTICS	1			1		
Output Capacitance	C _{obo}	_	4.5	pF	$V_{CB} = -5.0V$, $f = 1.0MHz$, $I_E = 0$	
Input Capacitance	C _{ibo}	_	10	pF	$V_{EB} = -0.5V$, $f = 1.0MHz$, $I_C = 0$	
Input Impedance	h _{ie}	2.0	12	kΩ		
Voltage Feedback Ratio	h _{re}	0.1	10	x 10 ⁻⁴	V _{CF} = -10V, I _C = -1.0mA, f = 1.0kHz	
Small Signal Current Gain	h _{fe}	100	400		VCE = -10 V, 1C = -1.0111A, 1 = 1.0K112	
Output Admittance	h _{oe}	3.0	60	μS		
Current Gain-Bandwidth Product	f⊤	250	_	MHz	$V_{CE} = -20V, I_{C} = -10mA, f = 100MHz$	
Noise Figure	NF	_	4.0	dB	$V_{CE} = -5.0V$, $I_{C} = -100\mu A$,	
					$R_S = 1.0k\Omega$, $f = 1.0kHz$	
SWITCHING CHARACTERISTICS	SWITCHING CHARACTERISTICS					
Delay Time	t _d	_	35	ns	$V_{CC} = -3.0V, I_{C} = -10mA,$	
Rise Time	t _r	_	35	ns	$V_{BE(off)} = 0.5V, I_{B1} = -1.0mA$	
Storage Time	ts	_	225	ns	$V_{CC} = -3.0V, I_{C} = -10mA,$	
Fall Time	t _f	_	75	ns	$I_{B1} = I_{B2} = -1.0 \text{mA}$	

4. Measured under pulsed condition. Pulse width = $300\mu s$. Duty cycle $\leq 2\%$.

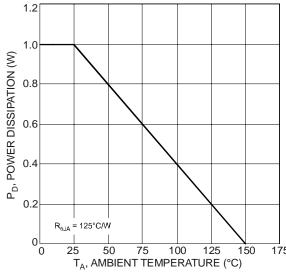
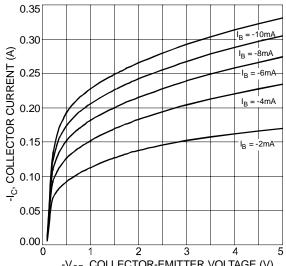
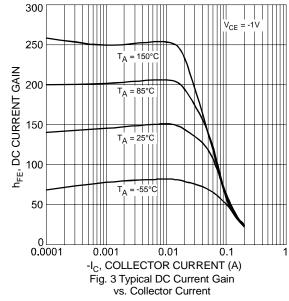


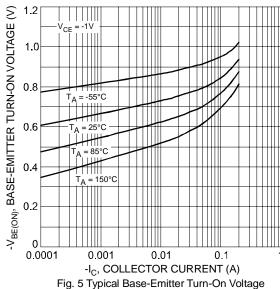
Fig. 1 Power Dissipation vs. Ambient Temperature (Note 3)

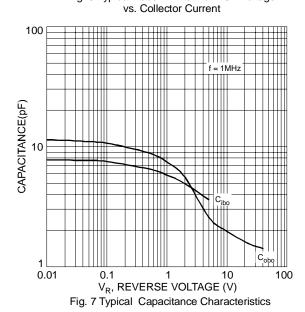


 $\hbox{-V}_{\text{CE}}, \hbox{COLLECTOR-EMITTER VOLTAGE (V)} \\ \hbox{Fig. 2 Typical Collector Current vs.Collector-Emitter Voltage}$









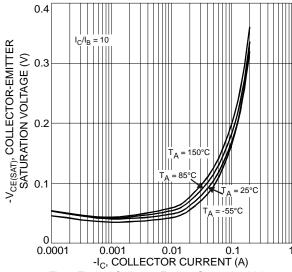


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

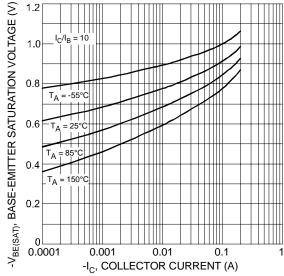


Fig. 6 Typical Base-Emitter Saturation Voltage vs. Collector Current

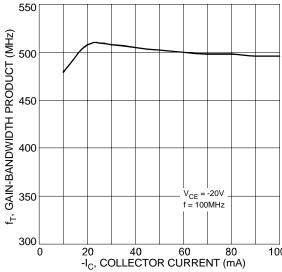


Fig. 8 Typical Gain-Bandwidth Product vs. Collector Current

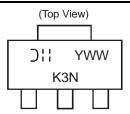


Ordering Information (Note 5)

Device	Packaging	Shipping
DXT3906-13	SOT89-3L	2500/Tape & Reel

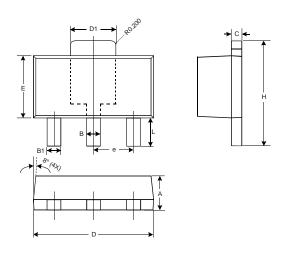
5. For packaging details, go to our website at http://www.diodes.com/ap02007.pdf.

Marking Information



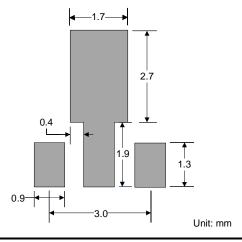
K3N = Product Type Marking Code Dil = Manufacturer's Marking Code YWW = Date Code Marking Y = Last digit of year ex: 7 = 2007 WW = Week code 01 - 52

Package Outline Dimensions



SOT89-3L					
Dim	Min	Max	Тур		
Α	1.40	1.60	1.50		
В	0.45	0.55	0.50		
B1	0.37	0.47	0.42		
С	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.50	1.70	1.60		
E	2.40	2.60	2.50		
е	_	_	1.50		
Н	3.95	4.25	4.10		
L	0.90	1.20	1.05		
All Dimensions in mm					

Suggested Pad Layout



IMPORTANT NOTICE

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. Diodes Incorporated does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on our website, harmless against all damages.

LIFE SUPPORT

Diodes Incorporated products are not authorized for use as critical components in life support devices or systems without the expressed written approval of the President of Diodes Incorporated.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Diodes Incorporated:

DXT3906-13